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# Synthesis Technology for CdSe/CdTe Heterojunctions and Characterization of Their Photoelectric Properties

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## Abstract

This paper presents the results of studying the photoelectric properties of CdSe/CdTe heterojunctions synthesized by the hot-wall epitaxy method. The CdSe/CdTe heterojunctions were manufactured by consecutive growth of CdSe and CdTe layers on a conductive ITO/glass substrate purchased from Solaronix Swiss. As ohmic contact for CdTe, Ni was deposited by thermal evaporation. The CdSe layer thickness (1–3  $\mu\text{m}$ ) was controlled according to the time of deposition of the layer. The temperature of the substrate and the source for CdTe growing were 400  $^{\circ}\text{C}$  and 520  $^{\circ}\text{C}$ , respectively and reached the thickness 15  $\mu\text{m}$ . The synthesis process for heterojunctions with CdTe layers includes the treatment of the entire structure in a  $\text{CdCl}_2$  solution, followed by annealing in air at a temperature of 450  $^{\circ}\text{C}$  for 30 min. Upon the deposition of CdTe layer, due to the diffusion of Se into the growing CdTe film, a transition layer of the  $\text{CdSe}_x\text{Te}_{1-x}$  solid solution is formed at the interface, evidenced by the spectral dependence of the photocurrent. The investigation of the current-voltage characteristics at different intensity of illuminations shown that nonideality factor  $n$  has a value of 1.7–2.0, which indicate a generation-recombination mechanism of current in the CdSe/CdTe heterojunctions. The best photovoltaic parameters for CdSe/CdTe heterojunctions were achieved for structures with thicker CdSe layer and are as follows:  $J_{\text{SC}} = 24.6 \text{ mA/cm}^2$ ,  $U_{\text{OC}} = 730 \text{ mV}$ ,  $\text{FF} = 0.5$ ,  $\eta = 7.6\%$ .

*Keywords: heterojunctions, solar cells, photovoltaic parameters*

## References

1. Simaschevici, A., Gorceac, L., Serban, D.: Conversia fotoltaic a energiei solare. Cent. Ed. USM, Kixinev (2002)



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2. Munshi, A.H., et al.: Polycrystalline CdSeTe/CdTe absorber cells with 28 mA/cm<sup>2</sup> shortcircuit current. *IEEE J. Photovolt* **8**(1), 310–314 (2018). <https://doi.org/10.1109/JPHOTOV.2017.2775139>
3. Swanson, D.E., Sites, J.R., Sampath, W.S.: Co-sublimation of Cd<sub>1-x</sub>Se<sub>x</sub>Te<sub>1-x</sub> layers for CdTe solar cells. *Sol. Energy Mater. Sol. Cells* **159**, 389–394 (2017). <https://doi.org/10.1016/j.solmat.2016.09.025>
4. Paudel, N.R., Yan, Y.: Enhancing the photo-currents of CdTe thin-film solar cells in both short and long wavelength regions. *Appl. Phys. Lett.* **105**(18), 183510 (2014). <https://doi.org/10.1063/1.4901532>
5. Fiducia, T., et al.: Understanding the role of selenium in defect passivation for highly efficient selenium-alloyed cadmium telluride solar cells. *Nat. Energy* **4**(6), 504–511 (2019). <https://doi.org/10.1038/s41560-019-0389-z>
6. Yang, X., et al.: Preparation and characterization of pulsed laser deposited CdS/CdSe bi-layer films for CdTe solar cell application. *Mater. Sci. Semicond. Process.* **48**, 27–32 (2016). <https://doi.org/10.1016/j.mssp.2016.03.009>
7. Poplawsky, J.D., et al.: Structural and compositional dependence of the CdTe<sub>x</sub>Se<sub>1-x</sub> alloy layer photoactivity in CdTe-based solar cells. *Nat. Commun.* **7**, 12537 (2016). <https://doi.org/10.1038/ncomms12537>
8. Baines, T., et al.: Incorporation of CdSe layers into CdTe thin film solar cells. *Sol. Energy Mater. Sol. Cells* **180**, 196–204 (2018). <https://doi.org/10.1016/j.solmat.2018.03.010>
9. Fang, X., et al.: Investigation of recombination mechanisms of CdTe solar cells with different buffer layers. *Sol. Energy Mater. Sol. Cells* **188**, 93–98 (2018). <https://doi.org/10.1016/j.solmat.2018.08.015>
10. Grice, C.R., Archer, A., Basnet, S., Paudel, N.R., Yan, Y.: Characterization of CdS/CdSe window layers in CdTe thin film solar cells. In: 43rd Photovoltaic Specialists Conference (PVSC) (2016). <https://doi.org/10.1109/PVSC.2016.7749859>
11. Green, M., Dunlop, E., Hohl-Ebinger, J., Yoshita, M., Kopidakis, N., Hao, X.: Solar cell efficiency tables (version 57). *Progress in Photovoltaics: Research and Applications* 1–13 (2020). <https://doi.org/10.1002/pip.3371>
12. Potlog, T.: The production of new types of CdTe photovoltaic devices with high efficiency. *Pub. By Research Signpost*, 87–121 (2014). ISBN: 978-81-308-0533-7
13. Potlog, T., Ghimpu, L., Gashin, P., Pudov, A., Sites, J.: Influence of annealing in different chlorides on the photovoltaic parameters of CdS/CdTe solar cells. *Sol. Energy Mater. Sol. Cells* **80**(3), 327–334 (2003). <https://doi.org/10.1016/j.solmat.2003.08.007>